

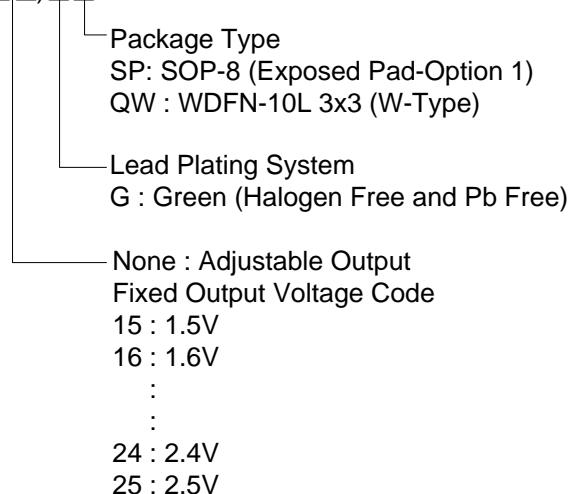
3A, Ultra-Low Dropout Voltage Regulator

General Description

The RT9059 is a high performance positive voltage regulator designed for use in applications requiring very low input voltage and very low dropout voltage at up to 3A. It operates with a VIN as low as 1V and VDD voltage 3V with programmable output voltage as low as 0.8V. The RT9059 features ultra low dropout, ideal for applications where VOUT is very close to VIN. Additionally, it has an enable pin to further reduce power dissipation while shutdown. The RT9059 provides excellent regulation over variations in line, load and temperature. The RT9059 provides a power good signal to indicate if the voltage level of V_O reaches 90% of its rating value.

Ordering Information

RT9059(-□□)□□



Note :

Richtek products are :

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- Suitable for use in SnPb or Pb-free soldering processes.

Marking Information

For marking information, contact our sales representative directly or through a Richtek distributor located in your area.

Features

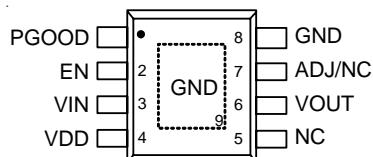
- Output Current up to 3A
- High Accuracy ADJ Voltage 1.5%
- Dropout Voltage 350mV @ 3A Typically
- VOUT Power Good Signal
- VOUT Pull Low Resistance when Disable
- Current Limiting Protection
- Thermal Shutdown Protection
- RoHS Compliant and Halogen Free

Applications

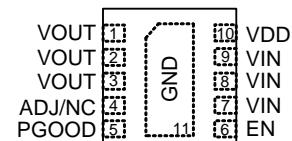
- Notebook PC Applications
- Motherboard Applications

Pin Configurations

(TOP VIEW)

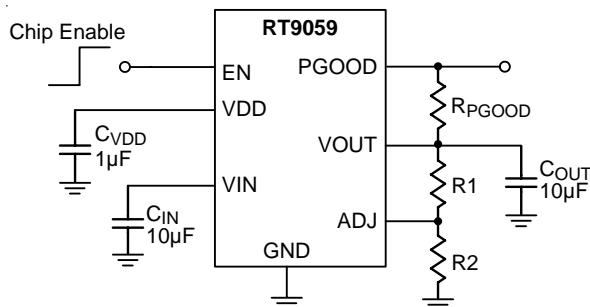


SOP-8 (Exposed Pad)



WDFN-10L 3x3

Typical Application Circuit



$$V_{OUT} = 0.8 \times (R1+R2)/R2$$

Figure 1. Adjustable Voltage Regulator

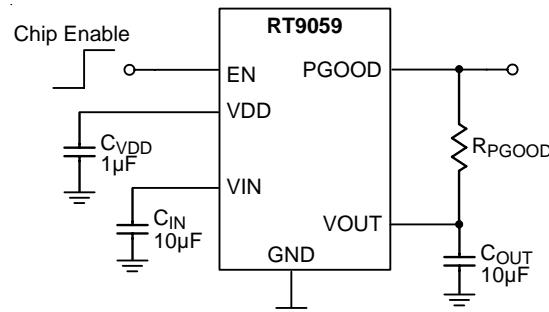
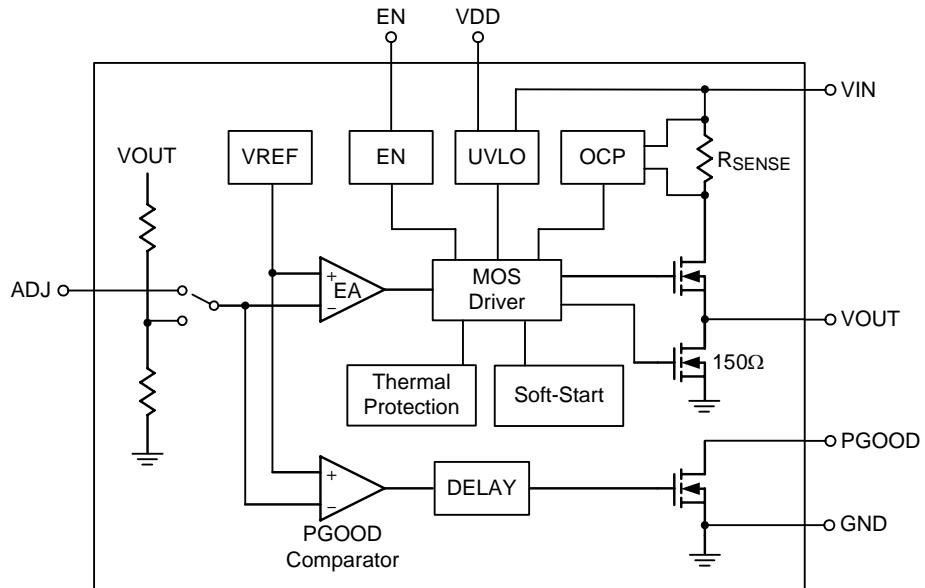


Figure 2. Fixed Voltage Regulator

Functional Pin Description

Pin No.				Pin Name	Pin Function		
SOP-8 (Exposed Pad)		WDFN-10L 3x3					
Adjustable Output Voltage	Fixed Output Voltage	Adjustable Output Voltage	Fixed Output Voltage				
1	1	5	5	PGOOD	Power Good Open Drain Output.		
2	2	6	6	EN	Enable Control Input.		
3	3	7, 8, 9	7, 8, 9	VIN	Supply Input Voltage.		
4	4	10	10	VDD	Supply Voltage of Control Circuit.		
5	5, 7	--	4	NC	No Internal Connection.		
6	6	1, 2, 3	1, 2, 3	VOUT	Output Voltage.		
7	--	4	--	ADJ	Output Voltage Setting. $V_{OUT} = V_{REF} \times (R1+R2)/R2$.		
8, 9 (Exposed Pad)	8, 9 (Exposed Pad)	11 (Exposed Pad)	11 (Exposed Pad)	GND	Ground. The exposed pad must be soldered to a large PCB and connected to GND for maximum power dissipation.		

Function Block Diagram



Absolute Maximum Ratings (Note 1)

- Supply Input Voltage, VIN to GND

DC	-0.3V to 6V
< 10ms	-0.3V to 7V
- Control Voltage, VDD to GND

DC	-0.3V to 6V
< 10ms	-0.3V to 7V
- Output Voltage, VOUT ----- -0.3V to 6V
- Chip Enable Voltage, EN ----- -0.3V to 6V
- Adjust Voltage, ADJ ----- -0.3V to 6V
- Power Good Voltage, V_{PGOOD} ----- -0.3V to 6V
- Power Dissipation, P_D @ T_A = 25°C

SOP-8 (Exposed Pad)	1.333W
WDFN-10L 3x3	1.429W
- Package Thermal Resistance (Note 2)

SOP-8 (Exposed Pad), θ _{JA}	75°C/W
SOP-8 (Exposed Pad), θ _{JC}	15°C/W
WDFN-10L 3x3, θ _{JA}	70°C/W
WDFN-10L 3x3, θ _{JC}	8.2°C/W
- Junction Temperature ----- 150°C
- Lead Temperature (Soldering, 10 sec.) ----- 260°C
- Storage Temperature Range ----- -65°C to 150°C
- ESD Susceptibility (Note 3)

HBM (Human Body Model)	2kV
MM (Machine Model)	200V

Recommended Operating Conditions (Note 4)

- Supply Input Voltage, VIN ----- 1V to 5V
- Control Voltage, VDD ----- 3V to 5.5V
- Junction Temperature Range ----- -40°C to 125°C
- Ambient Temperature Range ----- -40°C to 85°C

Electrical Characteristics(V_{DD} = 5V, C_{IN} = C_{OUT} = 10μF, C_{VDD} = 1μF, T_A = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
VDD Operation Range	V _{DD}		3	--	5.5	V
VDD POR Threshold	V _{POR_VDD}	V _{DD} Rising	2.4	2.7	3	V
VDD POR Falling Hysteresis	ΔV _{POR_VDD}	V _{DD} Falling	0.15	0.2	--	V
Input Voltage Range	V _{IN}		1	--	5.5	V
VIN POR Threshold	V _{POR_VIN}	V _{IN} Rising	0.7	0.8	0.9	V
VIN POR Falling Hysteresis	ΔV _{POR_VIN}	V _{IN} Falling	0.15	0.2	0.25	V
Quiescent Current	I _Q	EN On, No Load	--	0.6	1.2	mA

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reference Voltage	V _{REF}		0.788	0.8	0.812	V
Fixed Output Voltage Accuracy			-1.5	--	1.5	%
V _{OUT} Load Regulation	ΔV _{LOAD}	I _{OUT} = 1mA to 3A, V _{IN} = V _{OUT} +1V	--	0.5	1	%
OUT Line Regulation	ΔV _{LINe}	V _{DD} = 3.6V to 5.5V, V _{IN} = V _{OUT} +1V to 5V, I _{OUT} = 1mA	--	0.2	0.6	%
Dropout Voltage	V _{DROP}	I _{OUT} = 2A	--	250	350	mV
		I _{OUT} = 3A	--	350	450	
Current Limit	I _{LIM}	V _{IN} = 3.6V	3.1	3.6	4.2	A
Short Circuit Current	I _{SC}	V _{OUT} < 0.2V	1	1.4	1.8	A
V _{OUT} Pull Low Resistance	R _{PULL}	V _{EN} = 0V	--	150	--	Ω
Thermal Shutdown Temperature	T _{SD}		--	160	--	°C
Thermal Shutdown Recovery Temperature	T _{SDR}		--	90	--	°C
PGOOD Rising Threshold	V _{TH_PGOOD}	V _{OUT} Rising	--	90	--	%
PGOOD Hysteresis	ΔV _{TH_PGOOD}	V _{OUT} Falling	--	10	--	%
PGOOD Delay Time			--	1	1.5	ms
PGOOD Sink Capability	V _{PGOOD}	I _{SINK} = 10mA	--	0.2	0.4	V
EN Input Voltage	Logic-High	V _{IH}	1.2	--	--	V
	Logic-Low	V _{IL}	--	--	0.4	
EN Delay Time			0.3	0.85	1.4	ms
EN Pin Bias Current	I _{EN}	V _{EN} = 5V	--	12	--	μA
VDD Pin Shutdown Current	I _{SHDN_VDD}	V _{EN} = 0V	--	--	1	μA
VIN Pin Shutdown Current	I _{SHDN_VIN}	V _{EN} = 0V, V _{IN} = 5V	--	--	1	μA
Inrush Current	I _{INRUSH}	V _{OUT} = 1.8V, C _{OUT} = 10μF, I _{Load} = 1A	--	0.5	--	A
Soft-Start Time	t _{ss}		1.9	2.8	3.75	ms

Note 1. Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

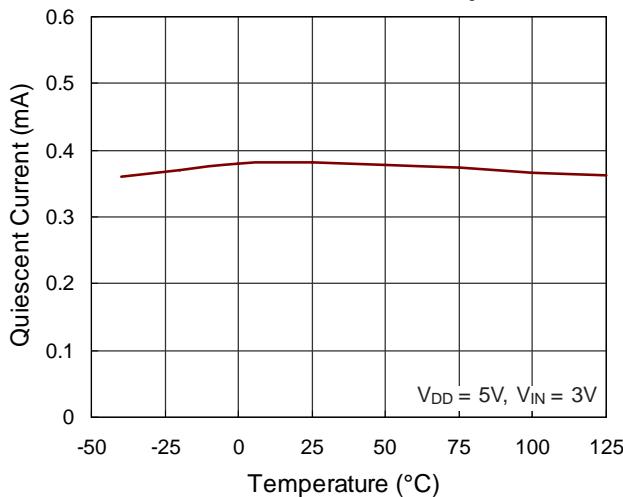
Note 2. θ_{JA} is measured at T_A = 25°C on a high effective thermal conductivity four-layer test board per JEDEC 51-7. θ_{JG} is measured at the exposed pad of the package.

Note 3. Devices are ESD sensitive. Handling precaution recommended.

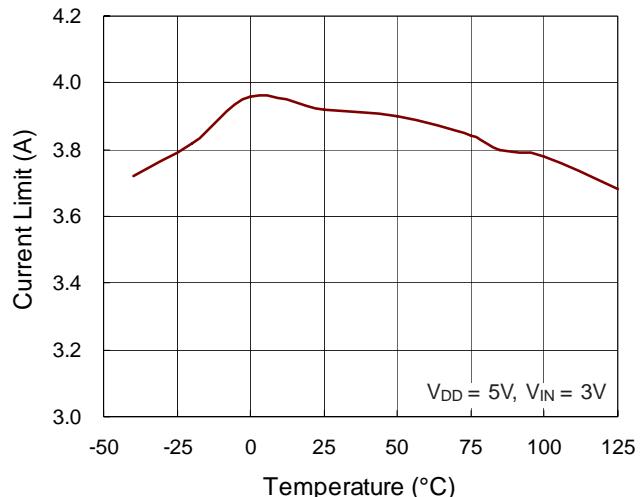
Note 4. The device is not guaranteed to function outside its operating conditions.

Typical Operating Characteristics

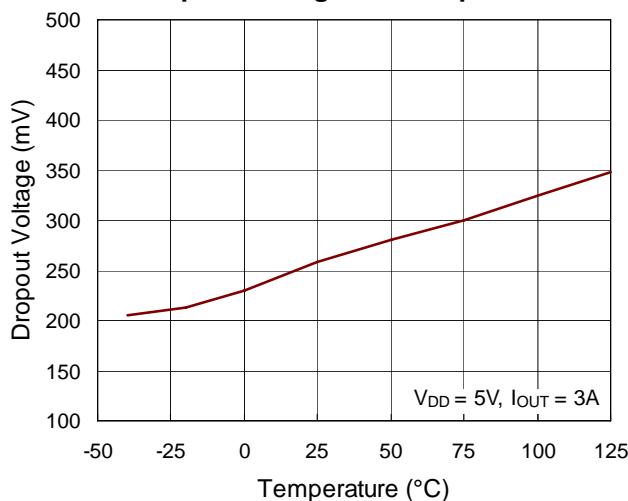
Quiescent Current vs. Temperature



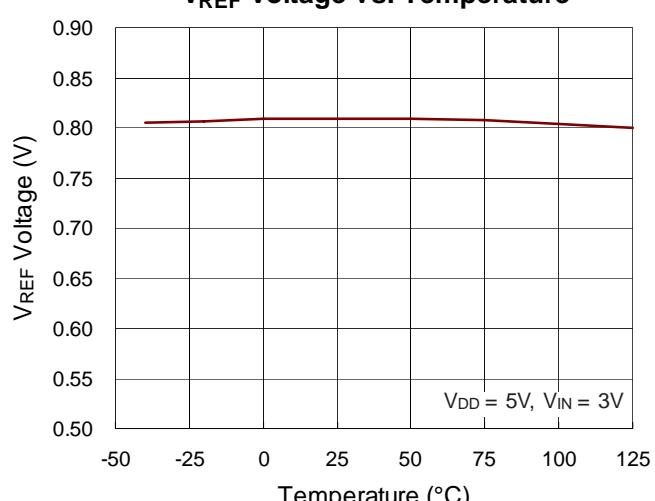
Current Limit vs. Temperature



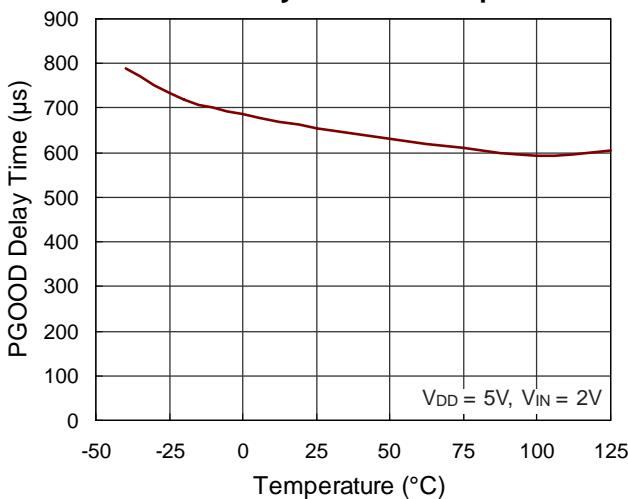
Dropout Voltage vs. Temperature



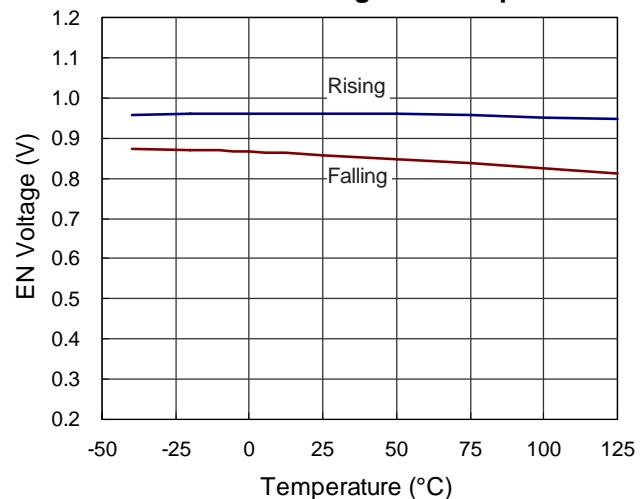
V_{REF} Voltage vs. Temperature

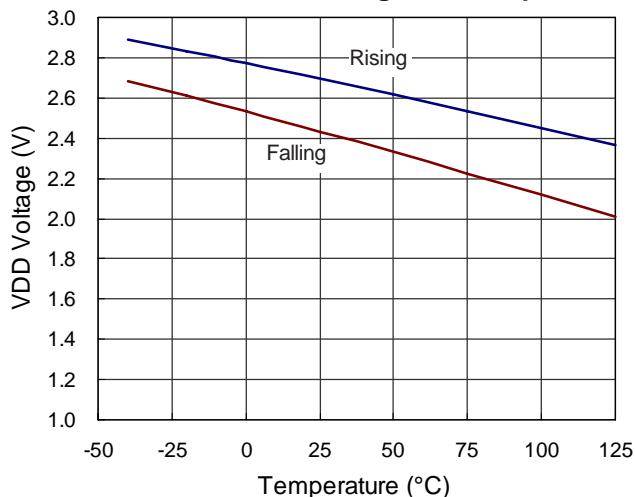
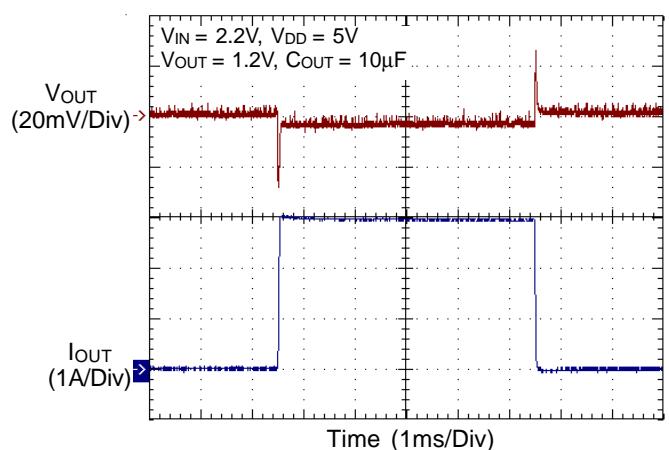
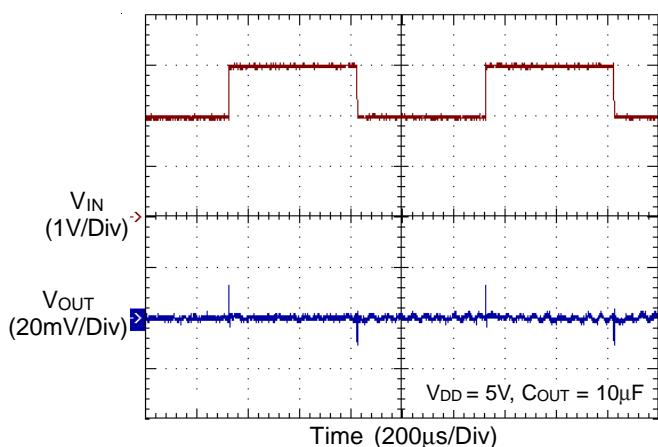
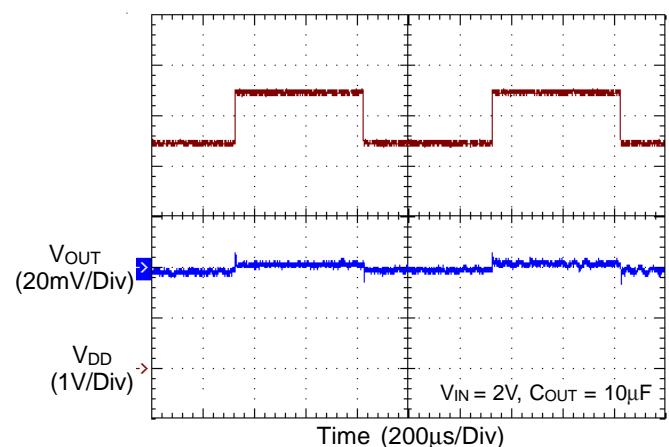
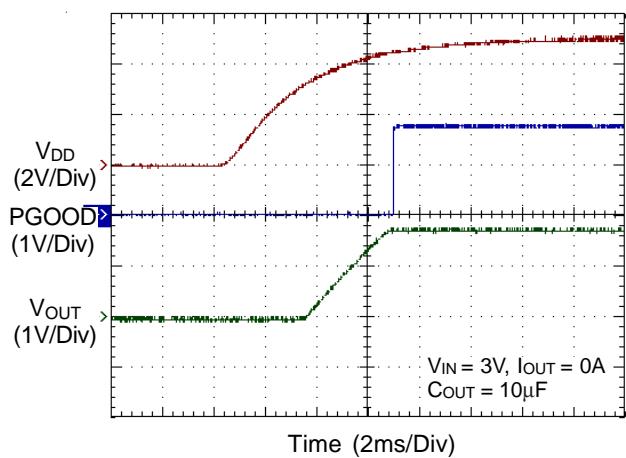
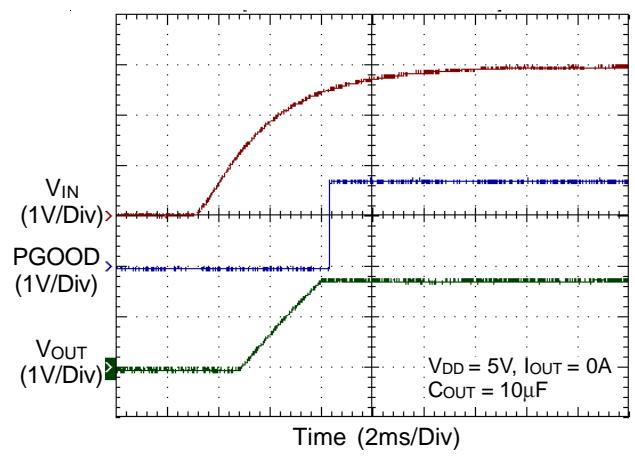


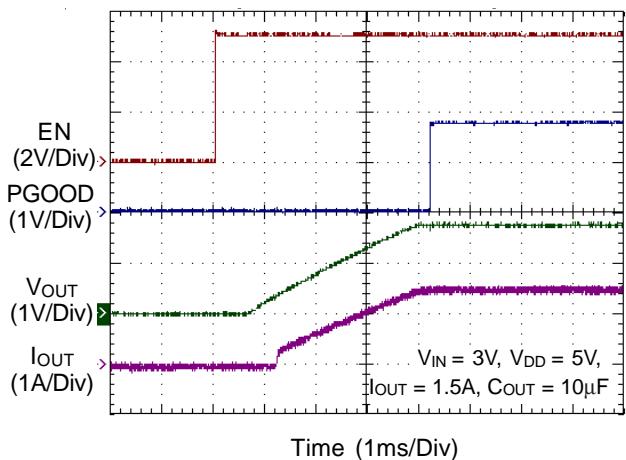
PGOOD Delay Time vs. Temperature



EN Threshold Voltage vs. Temperature



VDD POR Threshold Voltage vs. Temperature**Load Transient Response****VIN Line Transient Response****VDD Line Transient Response****Start Up from VDD****Start Up from VIN**

Start Up from Enable and PGOOD Delay

Applications Information

Adjustable Mode Operation

The output voltage of RT9059 is adjustable from 0.8V to VIN by external voltage divider resistors as shown in Typical Application Circuit (Figure 1). The value of resistors R1 and R2 should be more than 10kΩ to reduce the power loss. The output voltage can be calculated by the following equation :

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R1}{R2}\right)$$

where V_{REF} is the reference voltage (0.8V typical).

Enable

The RT9059 goes into shutdown mode when the EN pin is in the logic low condition. During this condition, the pass transistor, error amplifier, and band gap are turned off, reducing the supply current to 1μA typical. The RT9059 goes into operation mode when the EN pin is in the logic high condition. If the EN pin is floating, please notice the RT9059 internal initial logic level. For RT9059, the EN pin function pulls low level internally. So the regulator will be turned off when EN pin is floating.

Input Capacitor

Good bypassing is recommended from input to ground to improve AC performance. A 10μF input capacitor or greater located as close as possible to the IC is recommended.

Output Capacitor

The output capacitor must meet both requirements for minimum amount of capacitance and ESR in all LDOs application. The RT9059 is designed specifically to work with low ESR ceramic output capacitor in space-saving and performance consideration. Using a ceramic capacitor which value is at least 10μF on the RT9059 output ensures stability. The RT9059 still works well with output capacitor of other types due to the wide stable ESR range. Figure 3 shows the curves of allowable ESR range as a function of load current for various output capacitor values. Output capacitor of larger capacitance can reduce noise and improve load transient response, stability, and PSRR. The output capacitor should be located not more than 0.5 inch from the VOUT pin of the RT9059 and returned to a clean analog ground.

Region of Stable COUT ESR vs. Output Current

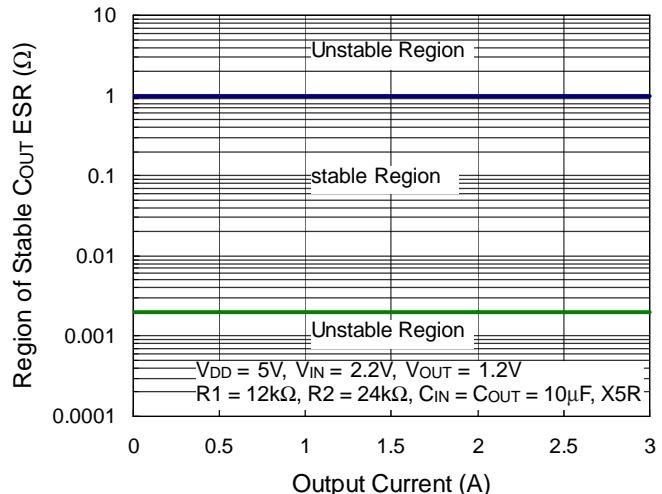


Figure 3. Region of Stable COUT ESR vs. Output Current

Current Limit

The RT9059 contains an independent current limit and the short circuit current protection to prevent unexpected applications. The current limit monitors and controls the pass transistor's gate voltage, minimum limiting the output current to 3.1A typical. When the output voltage is less than 0.2V, the short circuit current protection starts the current fold back function and maintains the loading current at maximum 1.8A. The output can be shorted to ground indefinitely without damaging the part.

Power Good

The power good function is an open-drain output. Connect 100kΩ pull up resistor to VOUT to obtain an output voltage. The PGOOD pin will output high immediately after the output voltage arrives 90% of normal output voltage.

Thermal Shutdown Protection

Thermal protection limits power dissipation to prevent IC over temperature in RT9059. When the operation junction temperature exceeds 160°C, the over temperature protection circuit starts the thermal shutdown function and turns the pass transistor off. The pass transistor turns on again after the junction temperature cools by 70°C.

Power Dissipation

For continuous operation, do not exceed absolute maximum operation junction temperature 125°C. The power dissipation definition in device is :

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_Q$$

The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surroundings airflow and temperature difference between junctions to ambient. The maximum power dissipation can be calculated by following formula :

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

Where $T_{J(MAX)}$ is the maximum operation junction temperature, T_A is the ambient temperature and the θ_{JA} is the junction to ambient thermal resistance.

For recommended operating conditions specification, the maximum junction temperature is 125°C. The junction to ambient thermal resistance for SOP-8 (Exposed Pad) package is 75°C/W on the standard JEDEC 51-7 (4 layers, 2S2P) thermal test board. The copper thickness is 2oz.

The maximum power dissipation at $T_A = 25^\circ\text{C}$ can be calculated by following formula :

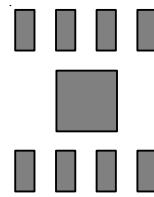
$$P_{D(MAX)} = (125^\circ\text{C} - 25^\circ\text{C}) / (75^\circ\text{C}/\text{W}) = 1.33\text{W}$$

(SOP-8 Exposed Pad on the minimum layout)

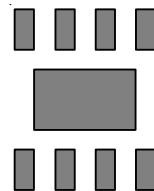
Layout Considerations

The thermal resistance θ_{JA} of SOP-8 (Exposed Pad) is determined by the package design and the PCB design. However, the package design had been designed. If possible, it's useful to increase thermal performance by the PCB design. The thermal resistance θ_{JA} can be decreased by adding a copper under the exposed pad of SOP-8 (Exposed Pad) package.

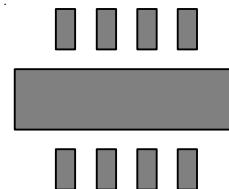
As shown in Figure 4, the amount of copper area to which the SOP-8 (Exposed Pad) is mounted affects thermal performance. When mounted to the standard SOP-8 (Exposed Pad) pad (Figure 4.a), θ_{JA} is 75°C/W. Adding copper area of pad under the SOP-8 (Exposed Pad) (Figure 4.b) reduces the θ_{JA} to 64°C/W. Even further, increasing the copper area of pad to 70mm² (Figure 4.e) reduces the θ_{JA} to 49°C/W.



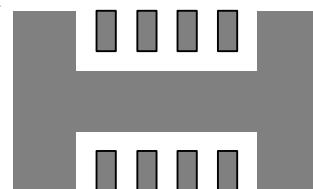
(a) Copper Area = (2.3 x 2.3) mm², $\theta_{JA} = 75^\circ\text{C}/\text{W}$



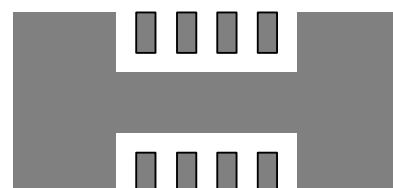
(b) Copper Area = 10mm², $\theta_{JA} = 64^\circ\text{C}/\text{W}$



(c) Copper Area = 30mm², $\theta_{JA} = 54^\circ\text{C}/\text{W}$



(d) Copper Area = 50mm², $\theta_{JA} = 51^\circ\text{C}/\text{W}$



(e) Copper Area = 70mm², $\theta_{JA} = 49^\circ\text{C}/\text{W}$

Figure 4. Thermal Resistance vs. Copper Area Layout Thermal Design

The maximum power dissipation depends on operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance θ_{JA} . The Figure 5 of derating curves allows the designer to see the effect of rising ambient temperature on the maximum power allowed.

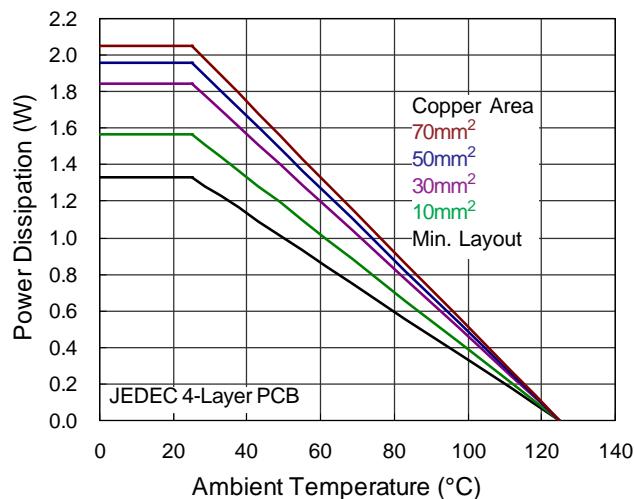
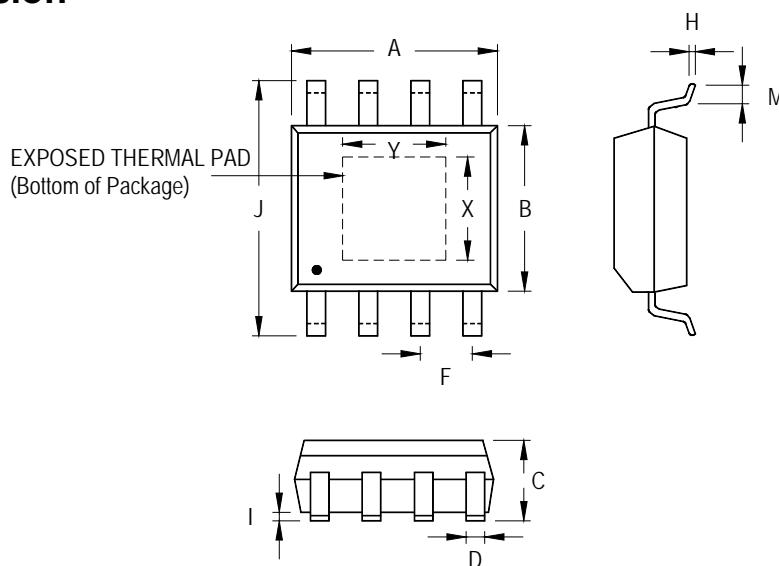


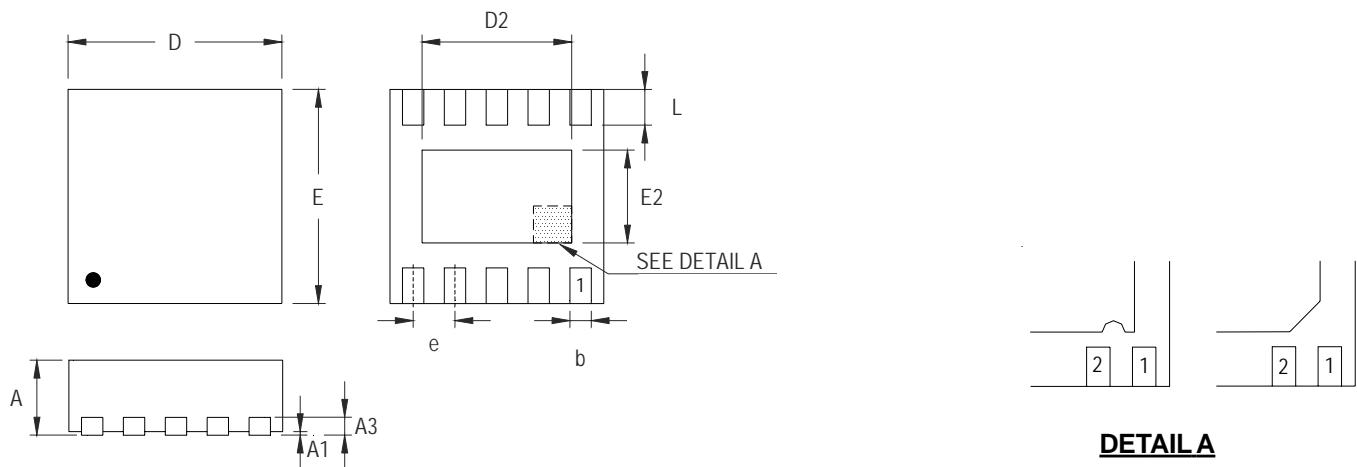
Figure 5. Derating Curve for Package

Outline Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.801	5.004	0.189	0.197
B	3.810	4.000	0.150	0.157
C	1.346	1.753	0.053	0.069
D	0.330	0.510	0.013	0.020
F	1.194	1.346	0.047	0.053
H	0.170	0.254	0.007	0.010
I	0.000	0.152	0.000	0.006
J	5.791	6.200	0.228	0.244
M	0.406	1.270	0.016	0.050
Option 1	X	2.000	2.300	0.079
	Y	2.000	2.300	0.079
Option 2	X	2.100	2.500	0.083
	Y	3.000	3.500	0.118

8-Lead SOP (Exposed Pad) Plastic Package

**DETAIL A**

Pin #1 ID and Tie Bar Mark Options

Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A3	0.175	0.250	0.007	0.010
b	0.180	0.300	0.007	0.012
D	2.950	3.050	0.116	0.120
D2	2.300	2.650	0.091	0.104
E	2.950	3.050	0.116	0.120
E2	1.500	1.750	0.059	0.069
e	0.500		0.020	
L	0.350	0.450	0.014	0.018

W-Type 10L DFN 3x3 Package**Richtek Technology Corporation**

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